

MediaTek Inc.

ITEM :

CRYSTAL OSCILLATOR

TYPE :

DSB211SDN

NOMINAL FREQUENCY :

26.000MHz

SPEC No. :

1XXD26000MAA

Please acknowledge receipt of this specification by signing and returning a copy to us.

	RECEIPT
DATE	
RECEIVED	(signature) (name)

General Manufacturer of Quartz Devices



675-0194 Japan Phone (81)79-425-3141 Fax (81)79-425-1134 http://www.kds.info/index_en.htm

A. Hishikawa C.ENG. H. Takase

ENG.

- 1. Device Name TCXO
- 2. Model Name DSB211SDN

3. Nominal Frequency 26.000 MHz

4. Mass 0.015g max.

5. Absolute Maximum Ratings

	Item	Symbol		Rating		unit		
1	Supply Voltage	Vcc		-0.3~+4.6		V		
2	Storage Temperature Range	T_stg		-40~+85	°C			
6. Recommended Operating Conditions								
	Item	Symbol	min.	typ.	max.	unit		
1	Supply Voltage	V _{CC}	+1.71	+1.8	+1.89	V		
			+2.09	+2.2	+2.31			
			+2.66	+2.8	+2.94			
2	Load Impedance (resistance part)	L _{OAD} R	9	10	11	kΩ		
	(parallel capacitance)	L _{OAD} C	9	10	11	рF		
3	Operating Temperature Range	T _{OPR}	-40	_	+85	°C		

7. Electrical Characteristics

 $(T_A=-40 \sim +85^{\circ}C, L_{OAD}_R//C=10k\Omega//10pF, V_{CC}=+1.8V \text{ or } +2.2 \text{ or } +2.8V, \text{ unless otherwise noted})$

	14	Quaditions		Limits			Nataa
	Item	Conditions		typ	max.	unit	Notes
1	Current Consumption		-	-	1.5	mA	
2	Output Level		0.8	I	-	V_{P-P}	1
3	Symmetry	GND level (DC cut)	40/60	-	60/40	%	
4	Frequency Stability						
	1.Tolerance	After 2 times reflow	-	-	±1.5	ppm	2,3
	2.vs Temperature	T _A =-30~+85°C	-	-	±0.5	ppm	4
		T _A =-40~-30°C	-	-	±1.0	ppm	4
	3.vs Drift Rate/Slope	@ 0.3°C/s			±10.0	ppb/s	
	4.vs Hysteresys		-	-	±0.6	ppm	
	5.vs Supply Voltage	V _{CC} =+1.8V±5%,+2.2V±5%,+2.8V±5%	-	-	±0.1	ppm	
	6.vs Load Variation	L _{OAD} _R//C=(10kΩ//10pF)±10%	-	-	±0.1	ppm	
	7.vs Aging	T _A =Room ambient	-	-	±1.0	ppm/year	
		T _A =Room ambient	-	-	±1.5	ppm/2years	
		T _A =Room ambient	-	-	±2.5	ppm/5years	
		T _A =Room ambient	-	-	±5.0	ppm/10years	
5	G Sensitivity	Gamma Vector of all 3axes from 30 to 1500Hz	-	-	±2.0	ppb/G	
6	Start Up Time	@90% of final V _{OUT} level	-	-	2.0	ms	
7	SSB Phase Noise	Relative to f0 level offset 1Hz	-	-	-50	dBc/Hz	
		Relative to f0 level offset 5Hz	-	-	-73	dBc/Hz	
		Relative to f0 level offset 10Hz	-	-	-80	dBc/Hz	
		Relative to f0 level offset 100Hz	-	-	-106	dBc/Hz	
		Relative to f0 level offset 1kHz	-	-	-134	dBc/Hz	
		Relative to f0 level offset 10kHz	-	-	-144	dBc/Hz	
		Relative to f0 level offset 100kHz	-	-	-152	dBc/Hz	

Notes

1. Clipped sine wave (DC-coupled)

2. Ref. to nominal frequency

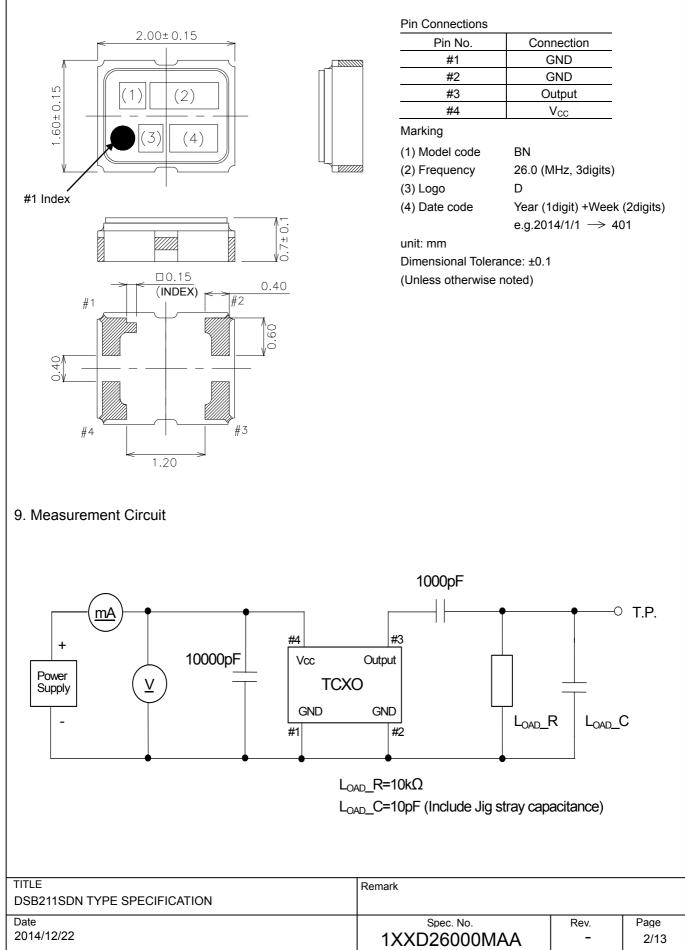
3. Please leave after reflow in 2h or more at room ambient.

4. Ref. to frequency (T_A =+25°C)

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8. Outline, Pin Connections

<u>Outline</u>



	14	I test is performed after 3times reflow (Cl				<u> </u>	
	Item	Description		Rec	luirements		
1	Drop	Natural drop (On concrete)					
		Mounting on the set or test fixture.(Tota	l weight 100g)				
		Height : 150cm		df/f=<±1.0pp	m		
		Direction : X,Y,Z, 6directions			,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		
		Test cycle : 3cycles					
		Reference specification : EIAJ-ED-470	2A Method5				
2	Vibration	Sweep range : 10~500Hz					
		Sweep speed : 11min/cycle					
		Amplitude : 1.5mm (10~55Hz)					
		Acceleration : 200m/s ² (55~500Hz)		df/f=<±0.5pp	m		
		Direction : X,Y,Z, 3directions					
		Test cycle : 10cycles					
		Reference specification : IEC 60068-2-	6				
3	Shock	Acceleration : 1000m/s ²	0				
5	SHOCK	Direction : X,Y,Z, 6directions					
		Direction : A, F,Z, our ections		df/f=<10 Epg			
				df/f=<±0.5pp	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		
		Test cycle : 3cycles/each directions	27				
4	DOD haved	Reference specification : IEC 60068-2-	21				
4	PCB bend	PWB : t=1.6mm					
	strength	Pressure speed : 1.0mm/s		df/f=<±0.5pp			
		Bend width : $1 \rightarrow 2 \rightarrow 3$ mm No visible damage.					
		Duration : 10±1s		No leak damage.			
		Reference specification : IEC 60068-2-	21 Ue1				
5	Adherence nature	PWB : t=1.6mm					
		Direction : X,Y, 2directions		df/f=<±0.5ppm			
		Pressure : 10N	No visible damage.				
		Duration : 10±1s		No leak dam	nage.		
		Reference specification : IEC 60068-2-	21 Ue3				
6	Package strength	Pressure : 10N		df/f=<±0.5ppm No mechanical damage.			
		Duration : 10±1s					
		Reference specification : IEC 60068-2-	77	No leak damage.			
7	Gross leak	It is immersed for 3min into +125±5°C			0		
		Chlorofluorocarbon (CFCs) liquid.		No continuo	us air bubbles	:	
		Reference specification : IEC 60068-2-	17				
8	Fine leak	It shall be measured by the helium leaf					
0		after pressurization for 60min by the pr	ization for 60min by the procesure				
		of $(3.92\pm0.49) \times 10^5$ Pa in a helium gas		Less than 1.0x10 ⁻⁹ Pa m ³ /s.			
		Reference specification : IEC 60068-2-					
9	Solderability		17	A	m conting of a		
9	Solderability	Solder bath temperature : +245±5°C		A new uniform coating of solde shall cover a minimum of 95%			
		Duration : 3±0.3s					
		Reference specification : IEC 60068-2-	58	of the surfac	e being imme	rsea.	
10	Resistance to	1) Solder iron method					
	soldering heat	Bit size : B(φ3) Bit temperature : +35)±10°C	df/f=<±0.5ppm			
		Duration : 3+1/-0s /each terminal		dV _{OUT} =<±0.2			
		It shall be measured after 2h at room te		No visible da	amage.		
		humidity. Reference specification : IEC	60068-2-20				
		2) Reflow					
		In refer to temperature profile shown in	clause13.	df/f=<±1.0pp	m		
		Test cycle : 3cycles		dV _{OUT} =<±0.2	2V _{P-P}		
		It shall be measured after 2h at room to	emperature,	No visible da	amage.		
		humidity. Reference specification : IEC			0		
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Requirements

The electrical characteristics

df/f=<±1.0ppm

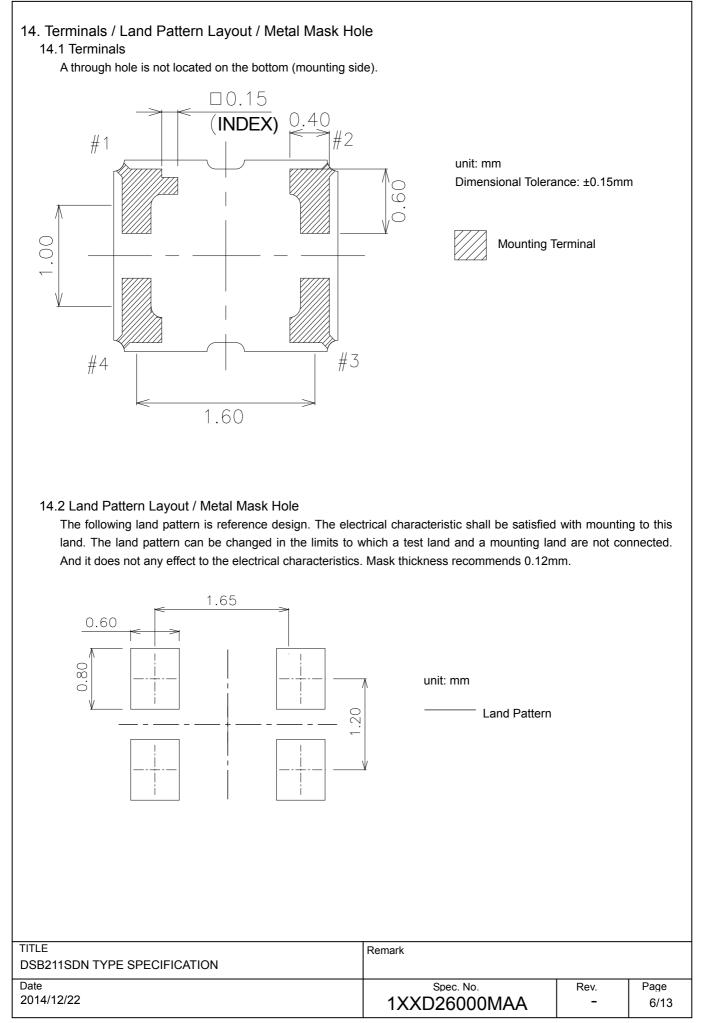
 $dV_{OUT} = <\pm 0.2V_{P-P}$

11. Environmental Characteristics All test is performed after 3times reflow (Clause13) Item Description 1 Low temperature Temperature : -40±3°C storage Duration: 1000h It shall be measured after 2h at room temperature, humidity. Reference specification : IEC 60068-2-1 Ab

		It shall be measured alter 21 at 100m temperature,	
		humidity. Reference specification : IEC 60068-2-1 Ab	are satisfied.
2	High temperature	Temperature : +85±2°C	df/f=<±1.0ppm
	storage	Duration : 1000h	$dV_{OUT} = < \pm 0.2V_{P-P}$
		It shall be measured after 2h at room temperature,	The electrical characteristics
		humidity. Reference specification : IEC 60068-2-2 Bb	are satisfied.
3	Humidity	Temperature : +85±2°C	df/f=<±1.0ppm
		R.H. 85±5%	$dV_{OUT} = <\pm 0.2V_{P-P}$
		Duration : 1000h	The electrical characteristics
		It shall be measured after 2h at room temperature,	are satisfied.
		humidity. Reference specification : IEC 60068-2-3	ale satisfied.
4	НТВ	Temperature : +85±2°C	df/f=<±1.0ppm
		Duration : 1000h	$dV_{OUT} = < \pm 0.2V_{P-P}$
		BIAS : Max value of supply voltage	The electrical characteristics
		It shall be measured after 2h at room temperature,	are satisfied.
		humidity. Reference specification : IEC 60068-2-2 Bb	
5	THB	Temperature : +40±2°C	
		R.H. 90~95%	df/f=<±1.0ppm
		Duration : 1000h	$dV_{OUT} = < \pm 0.2V_{P-P}$
		BIAS : Max value of supply voltage	The electrical characteristics
		It shall be measured after 2h at room temperature,	are satisfied.
		humidity. Reference specification : IEC 60068-2-3	
6	Thermal shock	Thermal shock : $-40\pm3^{\circ}C$: 0.5h \Leftrightarrow $+85\pm2^{\circ}C$: 0.5h	df/f=<±1.0ppm
		Test cycle : 200cycles	$dV_{OUT} = < \pm 0.2V_{P-P}$
		Shift time : 2~3min	The electrical characteristics
		It shall be measured after 2h at room temperature,	are satisfied.
		humidity. Reference specification : IEC pub.68-2-14.Na	
7	ESD	Model : Machine Model (MM)	
		V=±200V (C1=200pF, R1=0Ω)	df/f=<±1.0ppm
		Number of times : 3times	$dV_{OUT} = < \pm 0.2V_{P-P}$
		Each terminal except common terminal.	The electrical characteristics
		(Connect to test terminal)	are satisfied.
		Reference specification : EIA/JESD22-A114	
		Model : Human Body Model (HBM)	
		V=±1500V (C1=100pF, R1=1500Ω)	df/f=<±1.0ppm
		Number of times : 3times	$dV_{OUT} = <\pm 0.2V_{P-P}$
		Each terminal except common terminal.	The electrical characteristics
		(Connect to test terminal)	are satisfied.
		Reference specification : EIA/JESD22-A115	

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12. Flatness of Terminal When the component is placed on the flat surface, the gap	from the connecting terminal shall no	t exceed 0.05	mm.
	Gap : 0.05mm max.		
13. Reflow Profile	·		
+260°C			
Time			
1Preheat+1602Primary Heat+2203Peak+260			
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15. Packing Condition

- 15.1 Taping package
 - (1) Emboss tape format and dimensions See Fig.1
 - (2) Quantity on reel 2000pcs. max. / reel
 - (3) Taping specification
 - See Fig.2
 - No lack of a product. (4) Reel specification
 - See Fig.3
 - (5) Taping material list See right table.

15.2 Packing

- The products packed in the antistatic bag.
- *Moisture sensitivity level : IPC/JEDEC Standard J-STD-033 / Level 1
- No dry pack required and baking after re-storage is unnecessary.

15.3 Packing box

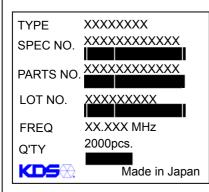
Max 10 reels/packing box. However, in the case of less than 10 reels, It is contained by any boxes. The space in a box is fill up with a cushion.

15.4 Label detail

A Lot label is put on a reel and a shipping label and Pb-Free label is put on a packing box.

Lot label		Shipping label		Pb-free Label
TYPE SPEC NO. PARTS NO. LOT NO. FREQ. Q'TY KDS	(Model Name) (Spec. Number) (User's Parts Number) (Lot Number) (Nominal Frequency) (Quantity) DAISHINKU CORP.	ITEM SPEC DELIVERY DATE Q'TY NOTES DAISHINKU CORF	(Model Name) (Spec. Number) (Delivery Date) (Quantity) (User's Parts Number)	Pb Pb-free

Lot label (Example)



Formation of a lot number

e.g. AH4101001			
<u> </u>	<u>_H_</u>	4101	001
Manufacturing site code	Product code	year/ month/ day	Serial No.

Taping material List

Emboss : PS (Conductivity)

Reel : PS (Conductivity)

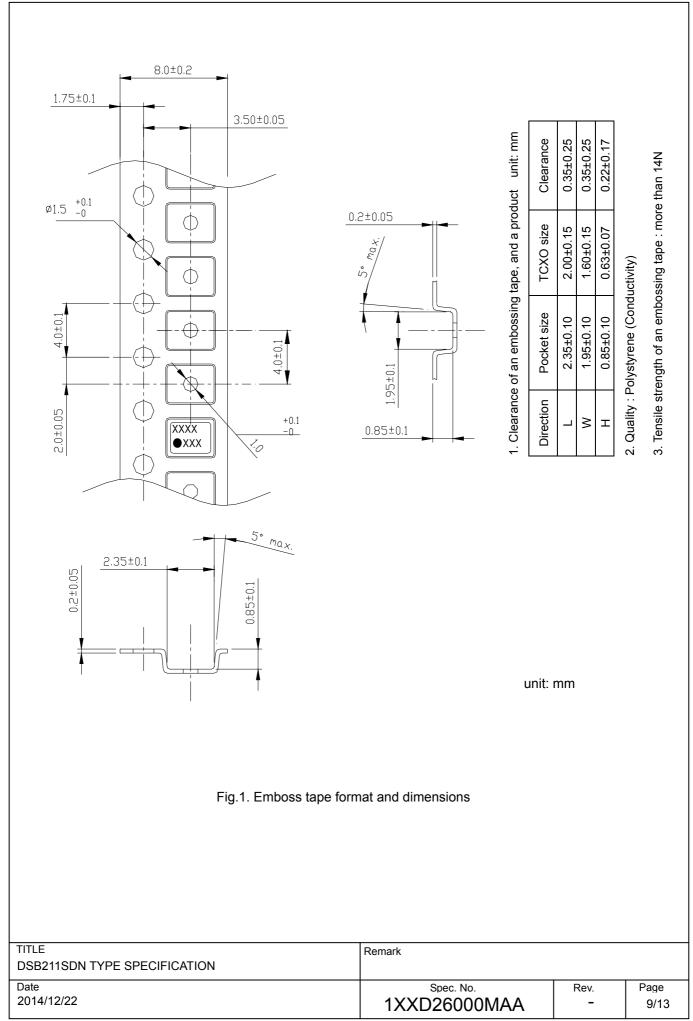
Cover Tape : PET + Olefin Resin (Conductivity)

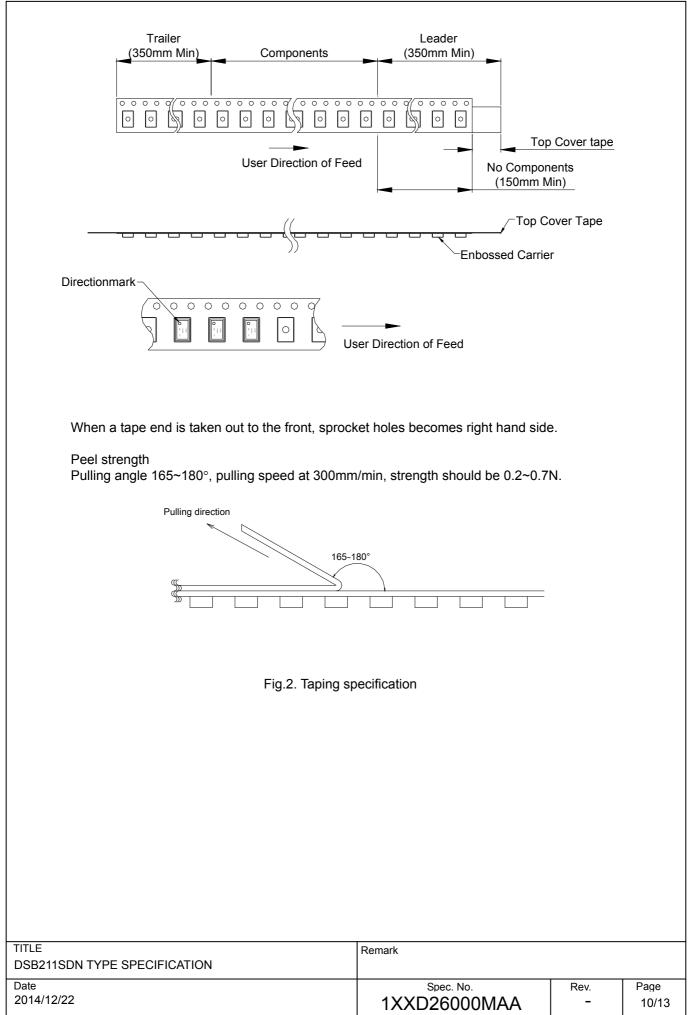
The notation method of a manufacture year, month, and day. (4digits alphanumeric character)

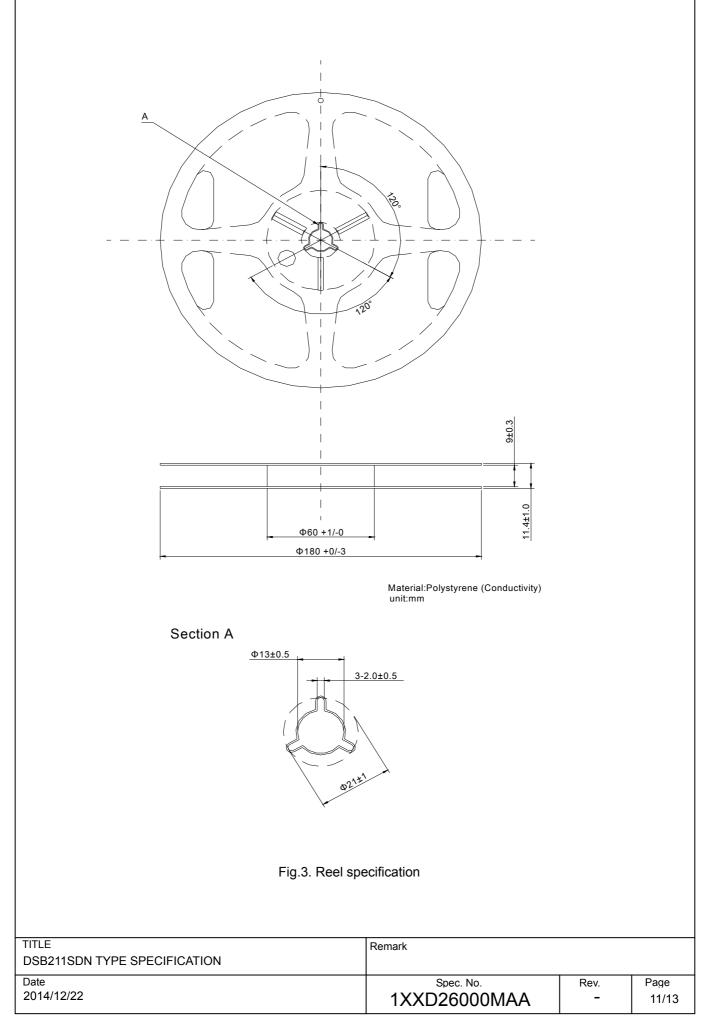
<u>YMDD</u> (4digits)				ts) e	e.g.) 20	01 <u>4</u> /0 <u>1</u>	_/ <u>01</u> →	4 <u>101</u>				
<u>Y</u> Year				1	1digit (Last digit of Year)							
<u>M</u> Month				ר ר	digit a	Iphanu	umeric	symbo	ol			
<u>DD</u> Day			2	digits	numer	ical ch	aracte	ers of d	lay			
Month	Jan.	Feb.	Mar.	Apr.	May.	Jun.	Jul.	Aug.	Sep.	Oct.	Nov.	Dec.
Symbol	1	2	3	4	5	6	7	8	9	0	Ν	D

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Lot Label				
	Air Cushion			
Antistatic Bag				
	Pb-free Label			
The product is packed up with the method which does not break in the handling by a shipping agent.				
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16. Notes on mounting and handling

16.1 Storage environment

- (1) The temperature and humidity of a storage place, Please give +5~+40°C and 40~85% as a standard.
- (2) Please use this product within one year from the packing label date of issue.
- (3) Please avoid the place which generates corrosive gas, and the place with much dirt.
- (4) Please keep it in a place with little temperature change.
- Dew condensation arises owing to a rapid temperature change and solderability becomes bad.
- 16.2 Be cautions to static electricity and high voltage.
- 16.3 This product has sufficient durability to fall and vibration. However, conditions may change to the fall after mounting to a PWB, and vibration. When you should drop on a floor the PWB which mounted the product or too much shock is added. Please use after a performance check.
- 16.4 Please check that the curvature of the substrate at the time of substrate cutting does not affect product. Moreover, especially when a product is near the position of a PWB guide pin, and the position of PWB break, be careful.
- 16.5 The part concerned does not correspond to washing.
- 16.6 Please repair at +260°C in 10s with hot air or +350°C in 5s with solder Iron.

17. Mandatory control

17.1 Ozone-depleting substance

It regulates by the U.S. air purifying method (November, 1990 establishment). ODS of CLASS1 and CLASS2 is not contained or used.

17.2 PBDE, PBBs

PBDE, PBBs are not contained into all the material currently used for this product.

17.3 RoHS

Following material restricted by RoHS (2011/65/EU) is not included or used. Lead, mercury, cadmium, hexavalent, chromium ,PBB and PBDE.

17.4 Law Concerning Examination and Regulation of Manufacture, etc. of Chemical Substances

All the material currently used for this product is based on "Law Concerning Examination and Regulation of Manufacture, etc. of Chemical Substances". It is a registered material.

17.5 Lead

Leads, such as solder, are not used for this product. (Lead Free)

17.6 About the existence of silver and mercury use

The silver of very small quantity is contained in the conductive adhesives used for adhesion of Blank. Moreover, mercury is used. It does not get down.

18. The country of origin / factory name / address

Country of origin:	Japan
Factory name:	DAISHINKU Corp. Tottori Production Div.
Address:	7-3-21 Wakabadai minami, Tottori 689-1112

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